

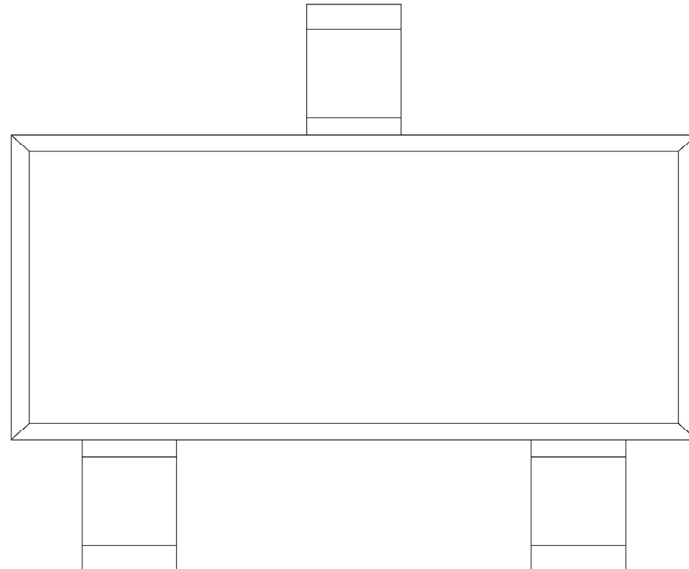
Rev.F Apr.-2017

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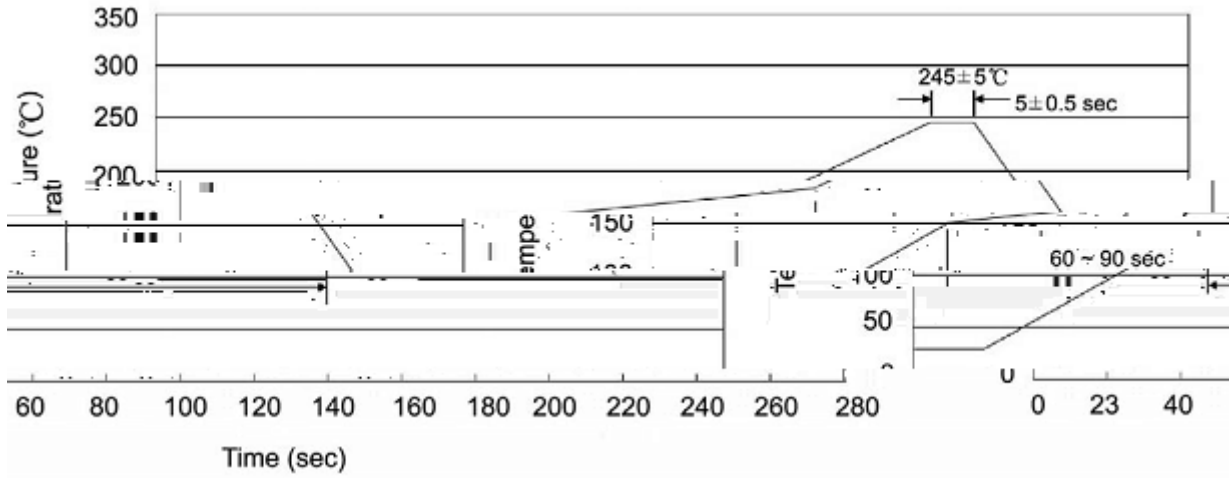
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-50	V
Collector to Emitter Voltage	V_{CEO}	-50	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current	I_C	-150	mA
Collector Power Dissipation	P_C	200	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

Parameter Symbol Test Conditions



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: 8 A

Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

1 25 150 60